Diode Semiconductor Device - Page 1 of 1



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Inc	losure Material:
Gla	ss
Ove	erall Length:
0.3	80 inches
Ter	minal Length:
1.5	00 inches
Ove	erall Diameter:
0.2	10 inches
Мо	unting Method:
Ter	minal
Fea	atures Provided:
Her	metically sealed case
Ser	niconductor Material:
Silio	con
Vol	tage Rating In Volts Per Characteristic:
2.0	reverse voltage, peak
Cu	rrent Rating Per Characteristic:
300	0.00 milliamperes forward current, average absolute
Ma	ximum Operating Tempurature Per Measurement Point:
150	0.0 degrees celsius ambient air
Ter	minal Type And Quantity:
2 u	ninsulated wire lead
She	elf Life:
N/a	
Uni	it Of Measure:
Der	militarization:
No	
Fiig	j:
A11	10a0